CMOS Digital Integrated Circuits Silicon Monolithic

74VHCT240AFT,74VHCT244AFT

1. Functional Description

Octal Bus Buffer
74VHCT240AFT: INVERTED, 3-STATE OUTPUTS
74VHCT244AFT: NON-INVERTED, 3-STATE OUTPUTS

2. General

The 74VHCT240AFT and 74VHCT244AFT are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C^2MOS technology. They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74VHCT240AFT is an inverting 3-state buffer having two active-low output enables. The 74VHCT244AFT is a non-inverting 3-state buffer, and has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.

The input voltage are compatible with $\ensuremath{\text{TTL}}$ output voltage.

These devices may be used as a level converter for interfacing $3.3~\mathrm{V}$ to $5~\mathrm{V}$ system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

3. Features

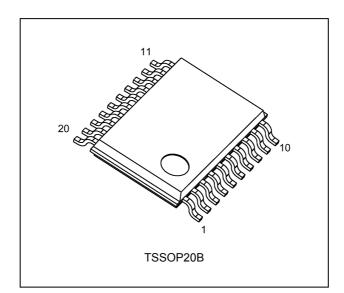
- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: Propagation delay time = 6.1 ns (typ.) at V_{CC} = 5.0 V
- (4) Quiescent supply current: I_{CC} = 4.0 μ A (max) at T_a = 25 °C
- (5) Compatible with TTL input: $V_{IL} = 0.8 V (max)$

$$V_{\rm IH}$$
 = 2.0 V (min)

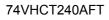
- (6) Power down protection is provided on all inputs and outputs.
- (7) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (8) Low noise: $V_{OLP} = 1.0 V (max)$
- (9) Pin and function compatible with the 74 series (ACT/HCT/AHCT etc.) 240/244 type.
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

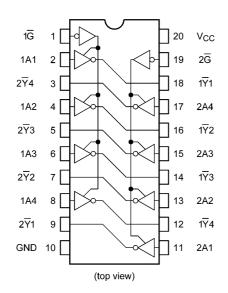
4. Packaging

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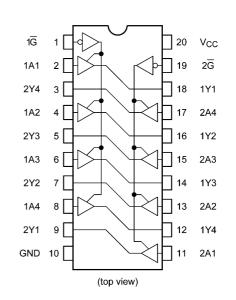


5. Pin Assignment

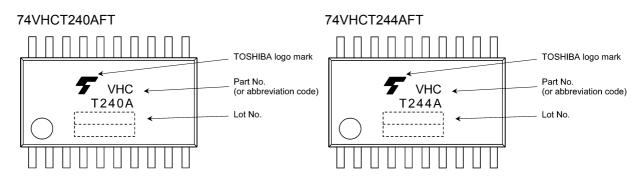




74VHCT244AFT



6. Marking

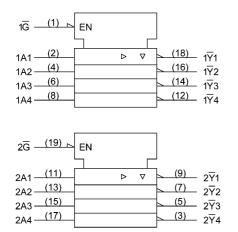


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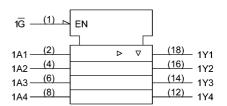
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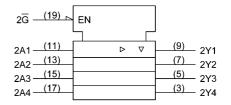
7. IEC Logic Symbol

74VHCT240AFT



74VHCT244AFT





8. Truth Table

Input G	Input An	Output Yn	Output Yn
L	L	L	Н
L	Н	Н	L
Н	Х	X Z	

X: Don't care

Z: High impedance

Yn: 74VHCT244AFT

Yn: 74VHCT240AFT

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{OUT}	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}		-20	mA
Output diode current	I _{ОК}	(Note 3)	±20	mA
Output current	I _{OUT}		±25	mA
V _{CC} /ground current	I _{CC}		±75	mA
Power dissipation	PD	(Note 4)	180	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in off-state.

Note 2: High (H) or Low (L) state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 3: V_{OUT} < GND, V_{OUT} > $_{VCC}$

Note 4: 180 mW in the range of $T_a = -40$ to 85 °C. From $T_a = 85$ to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		4.5 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	V
Output voltage	V _{OUT}	(Note 1)	0 to 5.5	V
		(Note 2)	0 to V _{CC}	
Operating temperature	T _{opr}		-40 to 125	°C
Input rise and fall times	dt/dv		0 to 20	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.

11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	_	V
Low-level input voltage	V _{IL}	_		4.5 to 5.5	_		0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.4	4.5	_	V
			I _{OH} = -8 mA	4.5	3.94	_	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.0	0.1	V
			I _{OL} = 8 mA	4.5	_	_	0.36	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND				_	±0.25	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_		±0.1	μA
Quiescent supply	I _{CC}	V _{IN} = V _{CC} or GND	V _{IN} = V _{CC} or GND		_	_	4.0	μA
current	I _{CCT}	Per input :V _{IN} = 3.4V Other input:V _{CC} or GND		5.5	_	—	1.35	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0		—	0.5	μA

11.2. DC Characteristics (Unless otherwise specified, Ta = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	VIH	—		4.5 to 5.5	2.0	—	V
Low-level input voltage	VIL	—		4.5 to 5.5		0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.4	—	V
			I _{OH} = -8 mA	4.5	3.80	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5		0.1	V
			I _{OL} = 8 mA	4.5	_	0.44	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	_	±2.50	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	40.0	μA
Quiescent supply current	I _{ССТ}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0	_	5.0	μΑ

11.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	—	V
Low-level input voltage	VIL	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	4.5	4.4	—	V
			I _{OH} = -8 mA	4.5	3.70	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.1	V
			I _{OL} = 8 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND			_	±10.0	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±2.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	80.0	μA
Quiescent supply current	I _{CCT}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0	_	20.0	μA

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11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	74VHCT240AFT	t _{PLH} ,t _{PHL}		—	5.0 ± 0.5	15	_	5.6	7.8	ns
						50	_	6.1	8.8	
	74VHCT244AFT	t _{PLH} ,t _{PHL}		—	5.0 ± 0.5	15	_	5.4	7.4	ns
						50	_	5.9	8.4	
3-state output enable time		t _{PZL} ,t _{PZH}		R _L = 1 kΩ	5.0 ± 0.5	15	_	7.7	10.4	ns
						50	_	8.2	11.4	
3-state output disable time		t _{PLZ} ,t _{PHZ}		R _L = 1 kΩ	5.0 ± 0.5	50	_	8.8	11.4	ns
Output skew		t_{osLH}, t_{osHL}	(Note 1)	_	5.0 ± 0.5	50	_	_	1.0	ns
Input capacitance		C _{IN}		_			_	4	10	pF
Output capacitance		C _{OUT}		_			_	9	_	pF
Power dissipation	74VHCT240AFT	C _{PD}	(Note 2)	_			_	19	_	pF
capacitance	74VHCT244AFT	C _{PD}	(Note 2)				_	18	_	

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per bit)

11.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	74VHCT240AFT	t _{PLH} ,t _{PHL}		_	5.0 ± 0.5	15	1.0	9.0	ns
						50	1.0	10.0	
	74VHCT244AFT	t _{PLH} ,t _{PHL}		_	5.0 ± 0.5	15	1.0	8.5	ns
						50	1.0	9.5	
3-state output enable time		t _{PZL} ,t _{PZH}		R _L = 1 kΩ	5.0 ± 0.5	15	1.0	12.0	ns
						50	1.0	13.0	
3-state output disable time		t _{PLZ} ,t _{PHZ}		R _L = 1 kΩ	5.0 ± 0.5	50	1.0	13.0	ns
Output skew		t _{osLH} ,t _{osHL}	(Note 1)	_	5.0 ± 0.5	50	_	1.0	ns
Input capacitance		C _{IN}		_			_	10	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

11.6. AC Characteristics

(Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 3 ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	74VHCT240AFT	t _{PLH} ,t _{PHL}		—	5.0 ± 0.5	15	1.0	10.0	ns
						50	1.0	11.0	
Propagation delay time	74VHCT244AFT	t _{PLH} ,t _{PHL}		_	5.0 ± 0.5	15	1.0	9.5	ns
						50	1.0	10.5	
3-state output enable time		t _{PZL} ,t _{PZH}		R _L = 1 kΩ	5.0 ± 0.5	15	1.0	13.0	ns
						50	1.0	14.5	
3-state output disable time		t _{PLZ} ,t _{PHZ}		R _L = 1 kΩ	5.0 ± 0.5	50	1.0	14.5	ns
Output skew		t_{osLH}, t_{osHL}	(Note 1)	—	5.0 ± 0.5	50	—	1.0	ns
Input capacitance		C _{IN}		_			_	10	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

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74VHCT240AFT,74VHCT244AFT

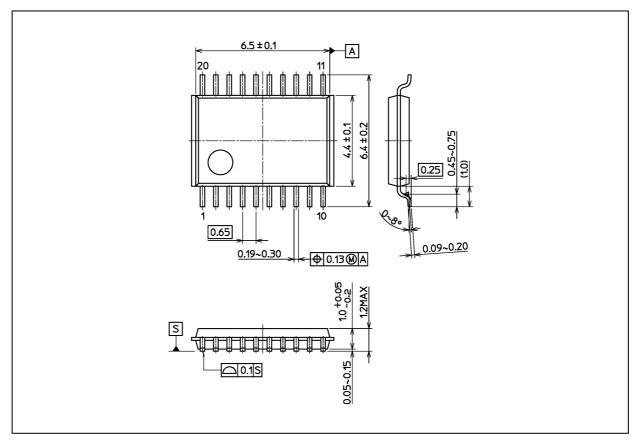
11.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	$V_{CC}(V)$	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.8	1.0	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.8	-1.0	
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0		2.0	
Maximum low-level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0		0.8	



Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	

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